FFP15S60S

October 2007 STEALTHTM II Rectifier

Boost Diode in continuous mode power factor corrections
Power switching circuits

+ High Speed Switching, t_{rr} < 35ns @ I_F = 15A

• High Reverse Voltage and High Reliability

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Features

· RoHS compliant

Applications

General Purpose

• Switching Mode Power Supply

A ANTEMENTATION





15A, 600V STEALTH[™] II Rectifier

reducing power loss in the switching transistors.

taxial planar construction.

The FFP15S60S is STEALTH™ II rectifier with soft recovery

characteristics. It is silicon nitride passivated ion-implanted epi-

This device is intended for use as freewheeling of boost diode in switching power supplies and other power switching applica-

tions. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits

1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current $@T_{C} = 123^{\circ}C$	15	А	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	150	А	
T _J , T _{STG}	Operating and Storage Temperature Range	-65 to +150	°C	

Thermal Characteristics

Symbol	Parameter	Ratings	Units
R_{\thetaJC}	Maximum Thermal Resistance, Junction to Case	1.3	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F15S60S	FFP15S60STU	TO-220-2L	-	-	50

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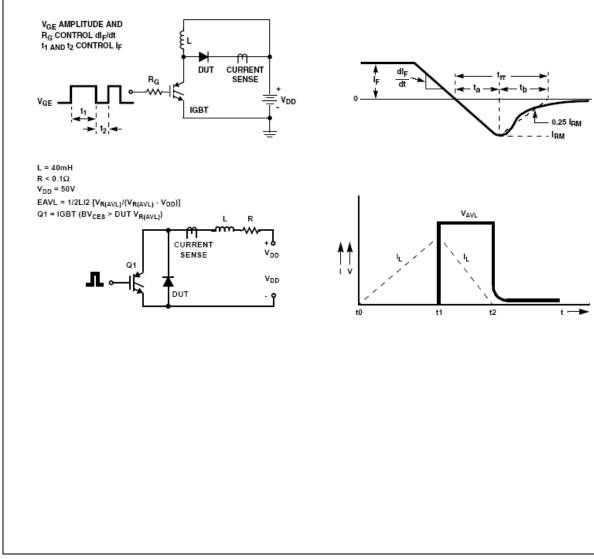
FFP15S60S

Electrical Characteristics $T_{C} = 25^{\circ}C$ unless otherwise noted

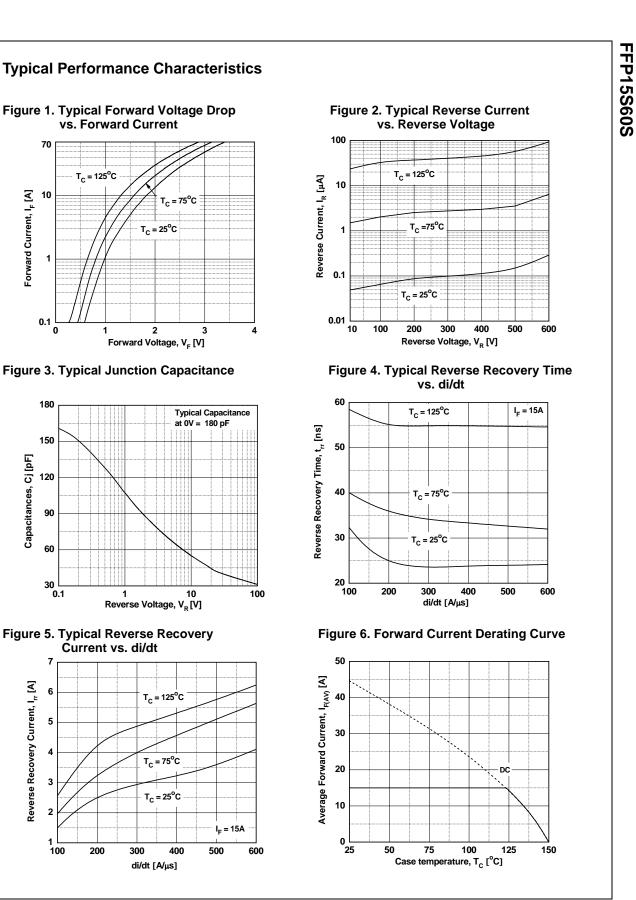
Symbol	Parameter		Min.	Тур.	Max.	Units
V _{FM} 1	I _F = 15A I _F = 15A	$T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$	-	2.1 1.6	2.6	V
I _{RM} 1	$V_{R} = 600V$ $V_{R} = 600V$	$T_{\rm C} = 25^{\circ}{\rm C}$ $T_{\rm C} = 125^{\circ}{\rm C}$	-	-	100 500	μΑ
t _{rr}	I _F = 1A, di/dt = 100A/µs, V _R = 30V	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	21	30	ns
t _{rr} I _{rr} S factor Q _{rr}	I _F = 15A, di/dt = 200A/µs, V _R = 390V	T _C = 25°C	-	23 2.5 0.7 29	35 - - -	ns A nC
t _{rr} I _{rr} S factor Q _{rr}	I _F = 15A, di/dt = 200A/µs, V _R = 390V	T _C = 125°C	-	55 4.3 1.1 118	-	ns A nC
W _{AVL}	Avalanche Energy (L = 40mH)	1	20	-	-	mJ

Notes: 1: Pulse: Test Pulse width = 300μ s, Duty Cycle = 2%

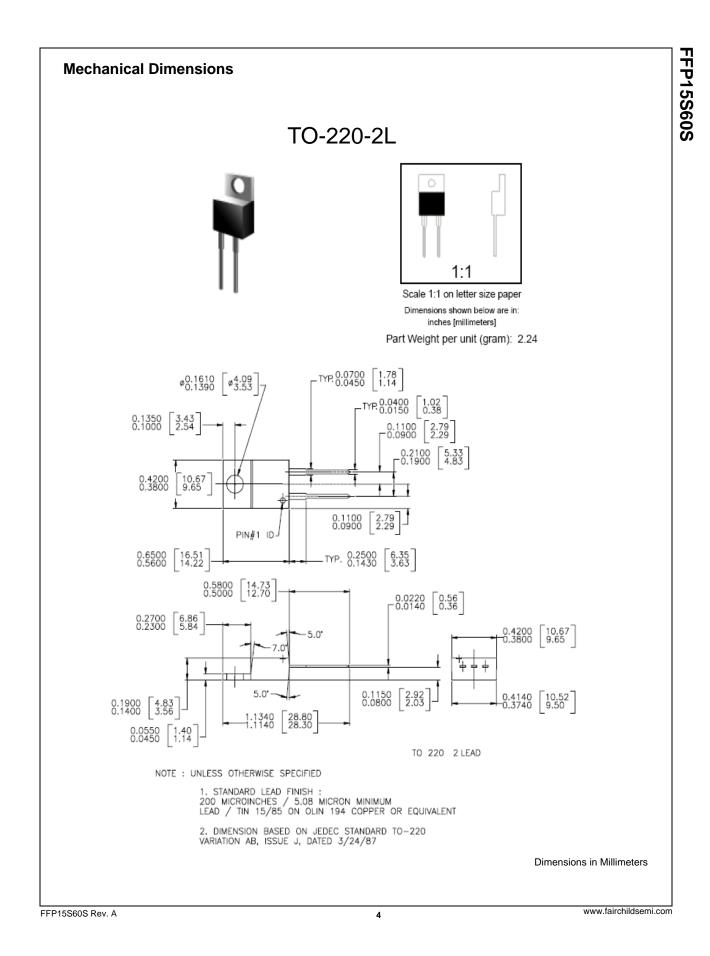
Test Circuit and Waveforms



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